



P-CHANNEL ENHANCEMENT MODE MOSFET

Product Summary

BVDSS	Rds(ON) Max	I _D Max T _A = +25°C
-30V	65mΩ @ V _{GS} = -10V	-3.8A
-307	99mΩ @ VGS = -4.5V	-3.0A

Description

This MOSFET has been designed to minimize the on-state resistance (RDS(ON)) yet maintain superior switching performance, making it ideal for high-efficiency power-management applications.

Applications

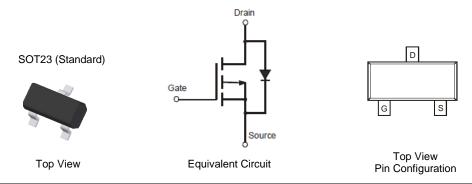
- Backlighting
- Power-management functions
- DC-DC converters

Features and Benefits

- Low Gate Threshold Voltage
- Low Input Capacitance
- Fast Switching Speed
- Low Input/Output Leakage
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- An automotive-compliant part is available under a separate datasheet (DMP3099LQ)

Mechanical Data

- Package: SOT23
- Package Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish—Matte Tin Annealed over Copper Leadframe. Solderable per MIL-STD-202, Method 208 @3
- Terminal Connections: See Diagram
- Weight: 0.008 grams (Approximate)



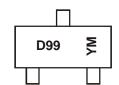
Ordering Information (Note 4)

Orderable Part Number	Baskaga	Paci	king
Orderable Part Number	Package	Qty.	Carrier
DMP3099L-7	SOT23 (Standard)	3000	Tape & Reel
DMP3099L-13	SOT23 (Standard)	10000	Tape & Reel

Notes:

- 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant.
- 2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
- 4. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/.

Marking Information



D99 = Product Type Marking Code YM = Date Code Marking Y = Year (ex: M = 2025)M = Month (ex: 9 = September)

Date Code Key

Year	2013	-	2025	2026	2027	2028	2029	2030	2031	2032	2033	2034
Code	Α	ı	М	Ν	Р	R	S	Т	J	٧	W	Χ
Month	Jan	Feb	Mar	Apr	May	Jun	Jul	Aug	Sep	Oct	Nov	Dec
Code	1	2	3	4	5	6	7	8	9	0	N	D



Maximum Ratings (@ T_A = +25°C, unless otherwise specified.)

Characterist	ic		Symbol	Value	Unit
Drain-Source Voltage			VDSS	-30	V
Gate-Source Voltage			Vgss	±20	V
Drain Current (Note 5) $V_{GS} = -10V$ Steady $T_A = +25^{\circ}C$ State $T_A = +70^{\circ}C$			lo	-3.8 -2.9	А
Pulsed Drain Current (Note 6)		I _{DM}	-11	Α	

Thermal Characteristics

Characteristic	Symbol	Value	Unit
Total Power Dissipation (Note 5)	PD	1.08	W
Thermal Resistance, Junction to Ambient @T _A = +25°C (Note 5)	Reja	115	°C/W
Operating and Storage Temperature Range	TJ, TSTG	-55 to +150	°C

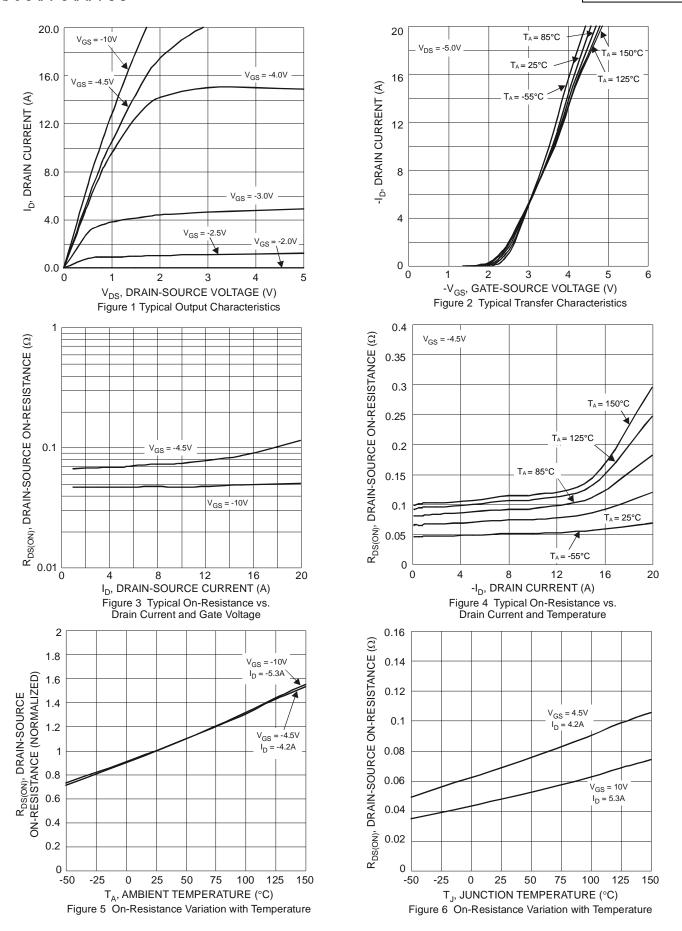
Electrical Characteristics (@ T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition	
OFF CHARACTERISTICS (Note 7)				•			
Drain-Source Breakdown Voltage	BVDSS	-30	1	_	٧	$V_{GS} = 0V, I_{D} = -250\mu A$	
Zero Gate Voltage Drain Current	IDSS	_	_	-800	nA	V _{DS} = -30V, V _{GS} = 0V	
Gate-Source Leakage	Igss	_	_	±100	nA	VGS = ±20V, VDS = 0V	
ON CHARACTERISTICS (Note 7)							
Gate Threshold Voltage	V _{GS(th)}	-1.0	1	-2.1	V	$V_{DS} = V_{GS}, I_D = -250\mu A$	
Static Drain-Source On-Resistance	Dagger			65	mΩ	Vgs = -10V, ID = -3.8A	
Static Drain-Source On-Resistance	RDS(ON)	_	_	99	11122	$V_{GS} = -4.5V$, $I_D = -3.0A$	
Forward Transfer Admittance	Y _{fs}	_	3.6	_	S	$V_{DS} = -5V$, $I_{D} = -2.7A$	
Diode Forward Voltage (Note 6)	V _{SD}	_	_	-1.26	V	V _{GS} = 0V, I _S = -2.7A	
DYNAMIC CHARACTERISTICS (Note 8)							
Input Capacitance	Ciss	_	563	_	pF		
Output Capacitance	Coss	_	48	_	pF	$V_{DS} = -25V, V_{GS} = 0V,$ f = 1.0MHz	
Reverse Transfer Capacitance	Crss	_	41	_	pF	1 - 1.000112	
Gate Resistance	Rg	_	10.3	_	Ω V _{GS} = 0V, V _{DS} = 0V, f = 1MHz		
SWITCHING CHARACTERISTICS (Note 8)							
Total Gate Charge	Qg	_	5.2	_		$V_{DS} = -15V$, $V_{GS} = -4.5V$, $I_{D} = -3.8A$	
		-	11	_	nC		
Gate-Source Charge	Qgs	_	1.7	_		V _{DS} = -15V, V _{GS} = -10V, I _D = -3.8A	
Gate-Drain Charge	Qgd	_	1.9	_			
Turn-On Delay Time	td(on)	_	4.8	_			
Rise Time	tr	_	5.0			V _{DS} = -15V, V _{GS} = -10V,	
Turn-Off Delay Time	td(off)	_	31	_	ns	$I_D = -1A, R_G = 6.0\Omega$	
Fall Time	t _f	_	15	_			

Notes: 5. Device mounted on FR-4 PCB on 2 oz., 0.5 inch² copper pads and t \leq 5 sec.

- 6. Pulse width \leq 10 μ S, Duty Cycle \leq 1%.
- 7. Short duration pulse test used to minimize self-heating effect.
- 8. Guaranteed by design. Not subject to production testing.







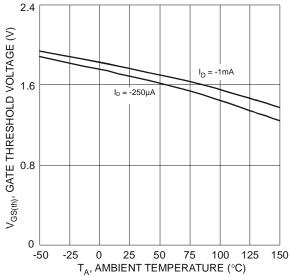
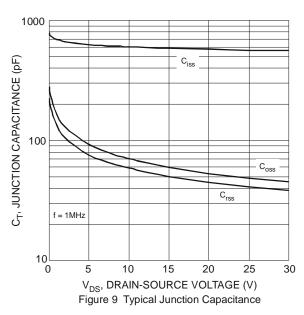
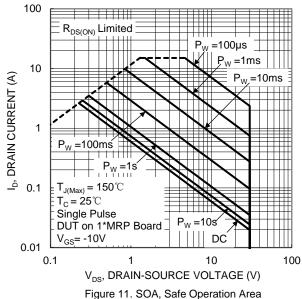
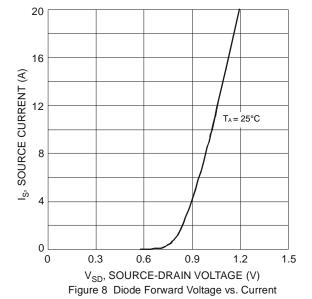
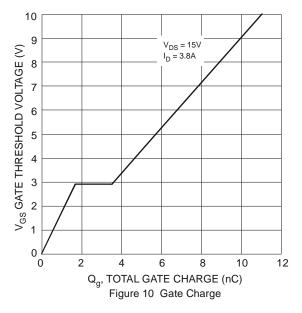


Figure 7 Gate Threshold Variation vs. Ambient Temperature







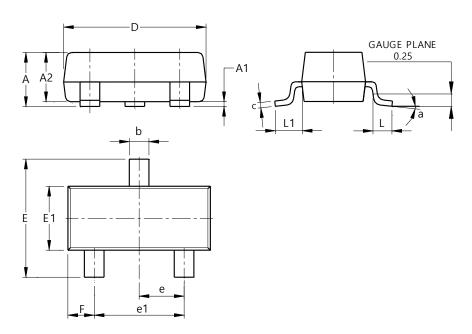




Package Outline Dimensions

Please see http://www.diodes.com/package-outlines.html for the latest version.

SOT23 (Standard)

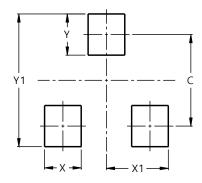


SOT23 (Standard)							
Dim	Min	Max	Тур				
Α	0.90	1.15	1.025				
A 1	0.00	0.10	0.05				
A2	0.85	1.10	0.975				
b	0.30	0.51	0.40				
С	0.080	0.202	0.11				
D	2.80	3.00	2.90				
Е	2.25	2.55	2.40				
E1	1.20	1.40	1.30				
е	0.89	1.03	0.915				
e1	1.78	2.05	1.83				
F	0.40	0.60	0.535				
L1	0.45	0.61	0.55				
L	0.25	0.55	0.40				
а	0°	8°					
All Dimensions in mm							

Suggested Pad Layout

Please see http://www.diodes.com/package-outlines.html for the latest version.

SOT23 (Standard)



Dimensions	Value (in mm)				
С	2.0				
Х	0.8				
X1	1.35				
Υ	0.9				
V1	2.0				



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